

**TC74LCX05F, TC74LCX05FN, TC74LCX05FT****LOW VOLTAGE HEX INVERTER****WITH 5 V TOLERANT INPUTS AND OUTPUTS (OPEN DRAIN)**

The TC74LCX05 is a high performance CMOS INVERTER. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

Pin configuration and function are the same as the TC74LCX04, but the TC74LCX05 has high performance MOS N-channel transistor. (Open-Drain outputs)

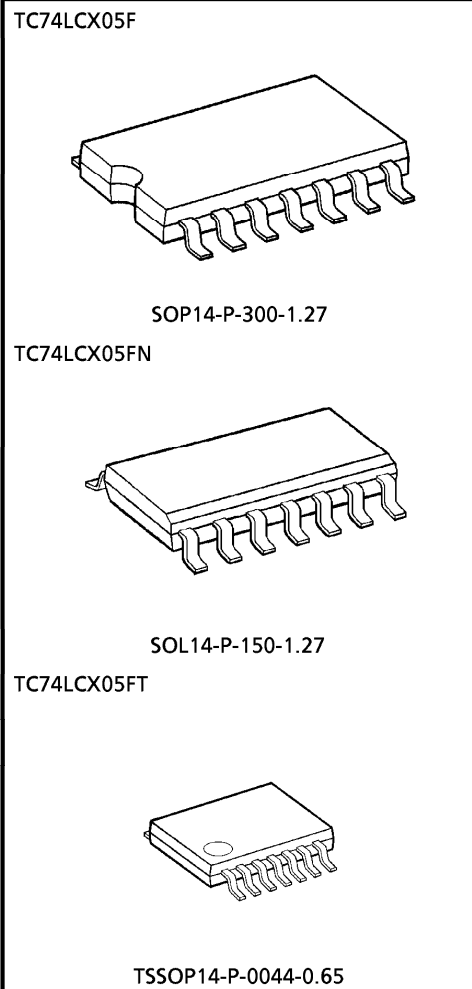
The device is designed for low-voltage (3.3 V)  $V_{CC}$  applications, but it could be used to interface to 5V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

**FEATURES**

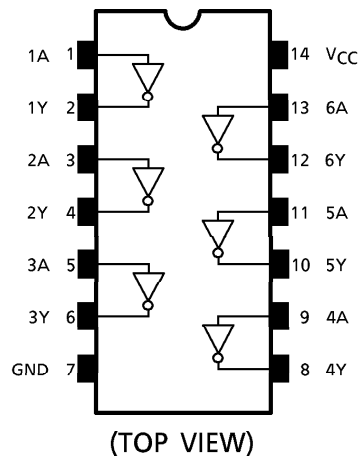
- Low voltage operation :  $V_{CC} = 2.0 \sim 3.6 \text{ V}$
- High speed operation :  $t_{pZ} = 5.0 \text{ ns (max)}$   
( $V_{CC} = 3.0 \sim 3.6 \text{ V}$ )
- Output current :  $I_{OL} = 24 \text{ mA (min)}$   
( $V_{CC} = 3.0 \text{ V}$ )
- Latch-up performance :  $-500 \text{ mA}$
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Open-Drain Outputs
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 05 type.

(Note) : The JEDEC SOP (FN) is not available in Japan.

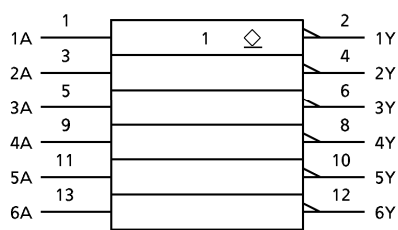
**Weight**

|                     |                 |
|---------------------|-----------------|
| SOP14-P-300-1.27    | : 0.18 g (Typ.) |
| SOL14-P-150-1.27    | : 0.12 g (Typ.) |
| TSSOP14-P-0044-0.65 | : 0.06 g (Typ.) |

PIN ASSIGNMENT



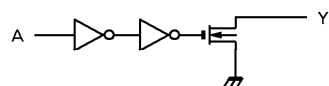
IEC LOGIC SYMBOL



TRUTH TABLE

| INPUTS | OUTPUTS |
|--------|---------|
| A      | Y       |
| L      | Z       |
| H      | L       |

SYSTEM DIAGRAM (per gate)



MAXIMUM RATINGS

| PARAMETER                   | SYMBOL           | RATING                                            | UNIT        |
|-----------------------------|------------------|---------------------------------------------------|-------------|
| Power Supply Voltage        | $V_{CC}$         | -0.5~7.0                                          | V           |
| DC Input Voltage            | $V_{IN}$         | -0.5~7.0                                          | V           |
| DC Output Voltage           | $V_{OUT}$        | -0.5~7.0 (Note 1)<br>-0.5~ $V_{CC}$ +0.5 (Note 2) | V           |
| Input Diode Current         | $I_{IK}$         | -50                                               | mA          |
| Output Diode Current        | $I_{OK}$         | -50 (Note 3)                                      | mA          |
| DC Output Current           | $I_{OUT}$        | 50                                                | mA          |
| Power Dissipation           | $P_D$            | 180                                               | mW          |
| DC $V_{CC}$ /Ground Current | $I_{CC}/I_{GND}$ | $\pm 100$                                         | mA          |
| Storage Temperature         | $T_{stg}$        | -65~150                                           | $^{\circ}C$ |

- (Note 1) : Output in Off-State  
(Note 2) : Low State.  $I_{OUT}$  absolute maximum rating must be observed.  
(Note 3) :  $V_{OUT} < GND$

## RECOMMENDED OPERATING CONDITIONS

| PARAMETER                | SYMBOL          | RATING               | UNIT |
|--------------------------|-----------------|----------------------|------|
| Supply Voltage           | $V_{CC}$        | 2.0~3.6              | V    |
|                          |                 | 1.5~3.6 (Note 4)     |      |
| Input Voltage            | $V_{IN}$        | 0~5.5                | V    |
| Output Voltage           | $V_{OUT}$       | 0~5.5 (Note 5)       | V    |
|                          |                 | 0~ $V_{CC}$ (Note 6) |      |
| Output Current           | $I_{OH}/I_{OL}$ | 24 (Note 7)          | mA   |
|                          |                 | 12 (Note 8)          |      |
| Operating Temperature    | $T_{opr}$       | -40~85               | °C   |
| Input Rise And Fall Time | $dt/dv$         | 0~10 (Note 9)        | ns/V |

(Note 4) : Data Retention Only

(Note 5) : Output in Off-State

(Note 6) : Low State

(Note 7) :  $V_{CC} = 3.0\sim 3.6\text{ V}$ (Note 8) :  $V_{CC} = 2.7\sim 3.0\text{ V}$ (Note 9) :  $V_{IN} = 0.8\sim 2.0\text{ V}$ ,  $V_{CC} = 3.0\text{ V}$ 

## ELECTRICAL CHARACTERISTICS

DC CHARACTERISTICS ( $T_a = -40\sim 85^\circ\text{C}$ )

| PARAMETER                             |           | SYMBOL           | TEST CONDITION                                                 |                          |         | V <sub>CC</sub> (V) | MIN  | MAX    | UNIT |
|---------------------------------------|-----------|------------------|----------------------------------------------------------------|--------------------------|---------|---------------------|------|--------|------|
| Input Voltage                         | "H" Level | V <sub>IH</sub>  |                                                                |                          |         | 2.7~3.6             | 2.0  | —      | V    |
|                                       | "L" Level | V <sub>IL</sub>  |                                                                |                          |         | 2.7~3.6             | —    | 0.8    |      |
| Output Voltage                        | "L" Level | V <sub>OL</sub>  | V <sub>IN</sub> = V <sub>IH</sub>                              | I <sub>OL</sub> = 100 μA | 2.7~3.6 | —                   | 0.2  | V      |      |
|                                       |           |                  |                                                                | I <sub>OL</sub> = 12 mA  | 2.7     | —                   | 0.4  |        |      |
|                                       |           |                  |                                                                | I <sub>OL</sub> = 16 mA  | 3.0     | —                   | 0.4  |        |      |
|                                       |           |                  |                                                                | I <sub>OL</sub> = 24 mA  | 3.0     | —                   | 0.55 |        |      |
| Input Leakage Current                 |           | I <sub>IN</sub>  | V <sub>IN</sub> = 0~5.5V                                       |                          |         | 2.7~3.6             | —    | ± 5.0  | μA   |
| Output Off-State Current              |           | I <sub>OZ</sub>  | V <sub>IN</sub> = V <sub>IL</sub> , V <sub>OUT</sub> = 0~5.5 V |                          |         | 2.7~3.6             | —    | ± 5.0  | μA   |
| Power Off Leakage Current             |           | I <sub>OFF</sub> | V <sub>IN</sub> / V <sub>OUT</sub> = 5.5 V                     |                          |         | 0                   | —    | 10.0   | μA   |
| Quiescent Supply Current              |           | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND                       |                          |         | 2.7~3.6             | —    | 10.0   | μA   |
|                                       |           |                  | V <sub>IN</sub> / V <sub>OUT</sub> = 3.6~5.5 V                 |                          |         | 2.7~3.6             | —    | ± 10.0 |      |
| Increase In I <sub>CC</sub> Per Input |           | ΔI <sub>CC</sub> | V <sub>IH</sub> = V <sub>CC</sub> - 0.6 V                      |                          |         | 2.7~3.6             | —    | 500    | μA   |

## AC CHARACTERISTICS (Ta = -40~85°C)

| PARAMETER             | SYMBOL            | TEST CONDITION | V <sub>CC</sub> (V) | MIN | MAX | UNIT |
|-----------------------|-------------------|----------------|---------------------|-----|-----|------|
|                       |                   |                |                     |     |     |      |
| Output Enable Time    | t <sub>pZL</sub>  | (Fig.1, 2)     | 2.7                 | 1.0 | 6.0 | ns   |
|                       |                   |                | 3.3 ± 0.3           | 0.8 | 5.0 |      |
| Output Disable Time   | t <sub>pLZ</sub>  | (Fig.1, 2)     | 2.7                 | 1.0 | 6.0 | ns   |
|                       |                   |                | 3.3 ± 0.3           | 0.8 | 5.0 |      |
| Output To Output Skew | t <sub>osZL</sub> | (Note 10)      | 2.7                 | —   | —   | ns   |
|                       |                   |                | 3.3 ± 0.3           | —   | 1.0 |      |

(Note 10) : Parameter guaranteed by design.

$$(t_{osZL} = |t_{pZLm} - t_{pZLn}|)$$

DYNAMIC SWITCHING CHARACTERISTICS (Ta = 25°C, Input t<sub>r</sub> = t<sub>f</sub> = 2.5 ns, C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 Ω)

| PARAMETER                                    | SYMBOL           | TEST CONDITION                                 | V <sub>CC</sub> (V) | TYP. | UNIT |
|----------------------------------------------|------------------|------------------------------------------------|---------------------|------|------|
|                                              |                  |                                                |                     |      |      |
| Quiet Output Maximum Dynamic V <sub>OL</sub> | V <sub>OLP</sub> | V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V | 3.3                 | 0.8  | V    |
| Quiet Output Minimum Dynamic V <sub>OL</sub> | V <sub>OLV</sub> | V <sub>IH</sub> = 3.3 V, V <sub>IL</sub> = 0 V | 3.3                 | 0.8  | V    |

## CAPACITIVE CHARACTERISTICS (Ta = 25°C)

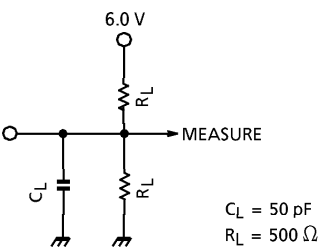
| PARAMETER                     | SYMBOL           | TEST CONDITION                     | V <sub>CC</sub> (V) | TYP. | UNIT |
|-------------------------------|------------------|------------------------------------|---------------------|------|------|
|                               |                  |                                    |                     |      |      |
| Input Capacitance             | C <sub>IN</sub>  | —                                  | 3.3                 | 7    | pF   |
| Output Capacitance            | C <sub>OUT</sub> |                                    | 3.3                 | 8    | pF   |
| Power Dissipation Capacitance | C <sub>PD</sub>  | f <sub>IN</sub> = 10 MHz (Note 11) | 3.3                 | 5    | pF   |

(Note 11) : C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

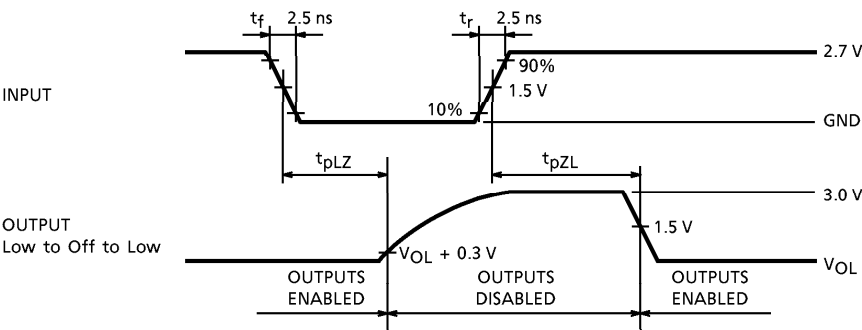
Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (Per gate)}$$

TEST CIRCUIT  
Fig.1

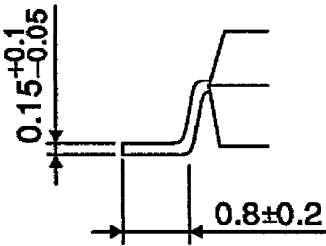
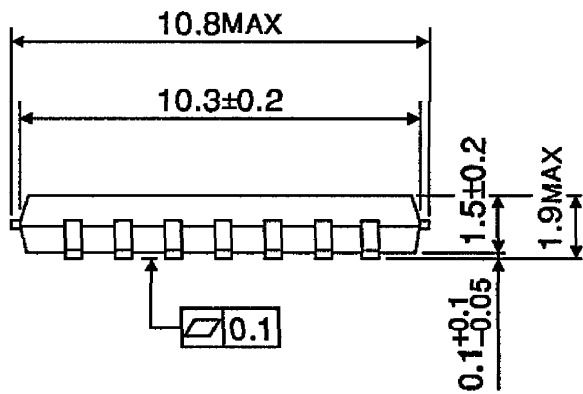
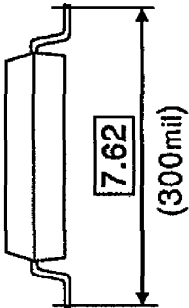
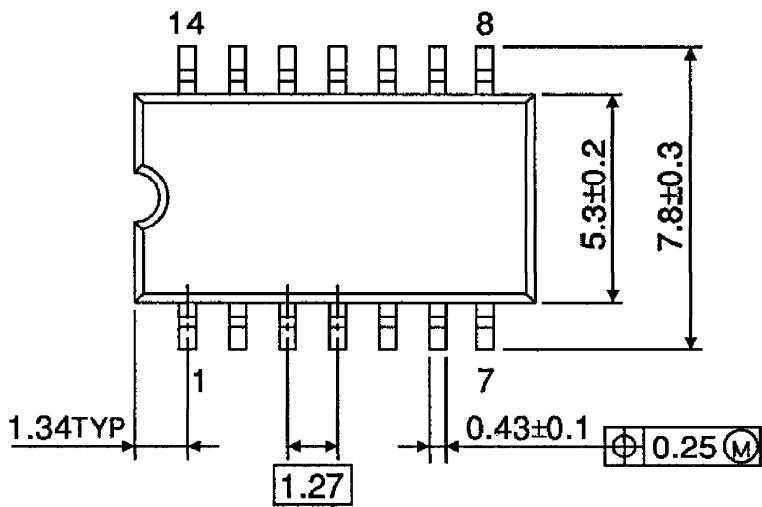


AC WAVEFORM  
Fig.2  $t_{pLZ}$ ,  $t_{pZL}$



PACKAGE DIMENSIONS  
SOP14-P-300-1.27

Unit : mm

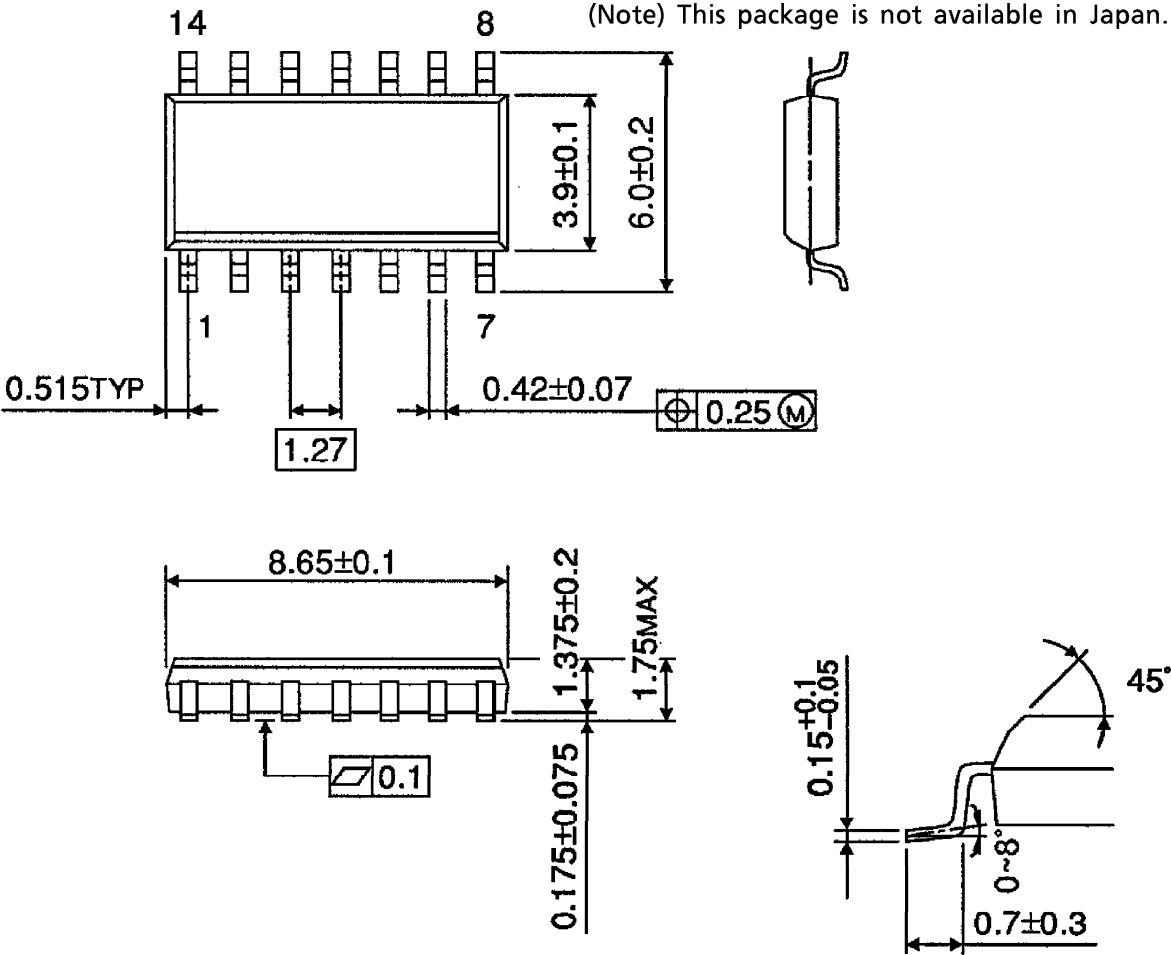


Weight : 0.18 g (Typ.)

PACKAGE DIMENSIONS  
SOL14-P-150-1.27

Unit : mm

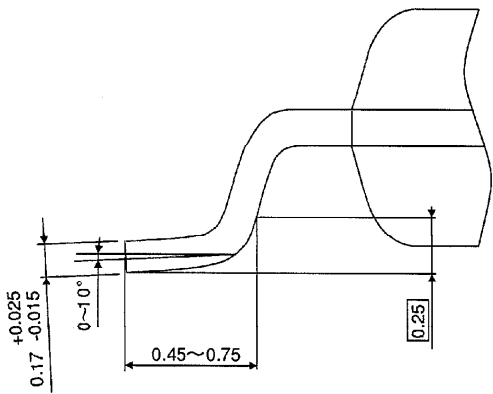
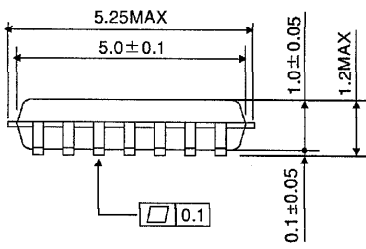
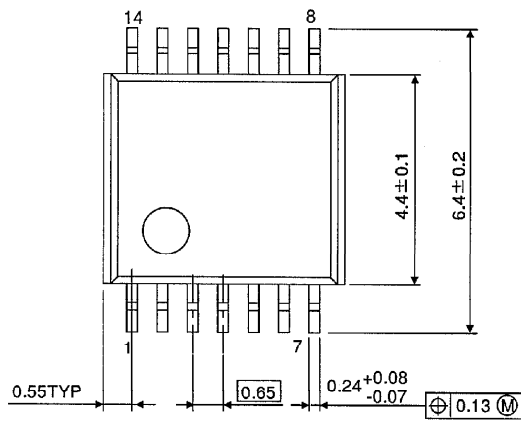
(Note) This package is not available in Japan.



Weight : 0.12 g (Typ.)

PACKAGE DIMENSIONS  
TSSOP14-P-0044-0.65

Unit : mm



Weight : 0.06 g (Typ.)



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000707EBA

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